

ESD Protection Diode

Micro-Packaged Diodes for ESD Protection

ESD7181, SZESD7181

The ESD7181 is designed to protect voltage sensitive components that require ultra-low capacitance from ESD and transient voltage events. Excellent clamping capability, low capacitance, low leakage, and fast response time make these parts ideal for ESD protection on designs where board space is at a premium. It has industry leading capacitance linearity over voltage making it ideal for RF applications.

Features

- Low Capacitance 0.3 pF (Typical)
- Low Clamping Voltage
- Small Body Outline Dimensions: (0.62 x 0.32 mm) – 0201
- Low Body Height: 0.3 mm
- Working Voltage: ±18.5 V
- Low Leakage < 1 nA (Typical)
- Low Insertion Loss
- Low Dynamic Resistance: < 1 Ω
- IEC61000-4-2 Level 4 ESD Protection
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- RF Signal ESD Protection
- Wireless Charger
- RF Switching, PA, and Antenna ESD Protection
- Near Field Communications

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) (Note 1) Air		15	kV
IEC 61000-4-2 (ESD) (Note 1) Contact		12	kV
IEC 61000-4-5 (ESD) (Note 2)		1	A
Total Power Dissipation (Note 3) @ T _A = 25°C	P _D	250	mW
Thermal Resistance, Junction-to-Ambient	R _{θJA}	400	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	T _L	260	°C

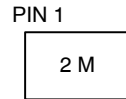
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Non-repetitive current pulse at T_A = 25°C, per IEC61000-4-2 waveform.
2. Non-repetitive current pulse at T_A = 25°C, per IEC61000-4-5 waveform.
3. Mounted with recommended minimum pad size, DC board FR-4



X3DFN2
CASE 152AF

MARKING DIAGRAM



2 = Specific Device Code
M = Date Code

*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping†
ESD7181MUT5G	X3DFN2 (Pb-Free)	10000 / Tape & Reel
SZESD7181MUT5G	X3DFN2 (Pb-Free)	15000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

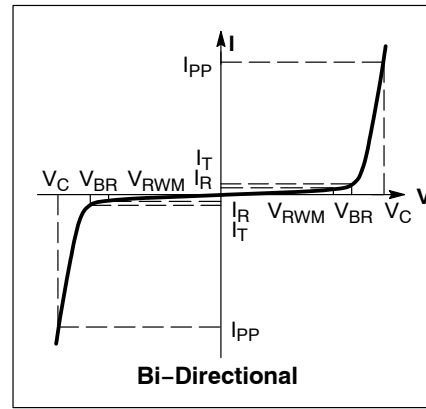
ESD7181, SZESD7181

ELECTRICAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Maximum Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current

*See Application Note AND8308/D for detailed explanations of datasheet parameters.



ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
AC Working Voltage	V_{RWM}		-	-	± 18.5	V
Breakdown Voltage (Note 4)	V_{BR}	$I_T = 1 \text{ mA}$	20.5	-	35	V
AC Reverse Current	I_R	$V_{RWM} = \pm 18.5 \text{ V}$	-	< 1	50	nA
Clamping Voltage (Note 5)	V_C	IEC61000-4-2, $\pm 8 \text{ kV}$ Contact	See Figures 1 and 2			
Clamping Voltage TLP (Note 6)	V_C	$I_{PP} = 8 \text{ A}$ $I_{PP} = 16 \text{ A}$ $I_{PP} = -8 \text{ A}$ $I_{PP} = -16 \text{ A}$		37.7 40.4 -38.4 -41.1		V
Clamping Voltage (Note 6)	V_C	$I_{PP} = 1 \text{ A @ } 8/20 \mu\text{s}$	-	35	-	V
Junction Capacitance	C_J	$V_R = 0 \text{ V}, f = 1 \text{ MHz}$ $V_R = 0 \text{ V}, f = 1 \text{ GHz}$	0.1 0.1	0.3 0.15	0.50 0.50	pF
Dynamic Resistance	R_{DYN}	TLP Pulse		0.44		Ω
Insertion Loss		$f = 1 \text{ MHz}$ $f = 8.5 \text{ GHz}$		-0.045 -0.335		dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Breakdown voltage is tested from pin 1 to 2 and pin 2 to 1.
5. For test procedure see Figures 3 and 4 and application note AND8307/D.
6. ANSI/ESD STM5.5.1 – Electrostatic Discharge Sensitivity Testing using Transmission Line Pulse (TLP) Model.
TLP conditions: $Z_0 = 50 \Omega$, $t_p = 100 \text{ ns}$, $t_r = 4 \text{ ns}$, averaging window; $t_1 = 30 \text{ ns}$ to $t_2 = 60 \text{ ns}$.

TYPICAL CHARACTERISTICS

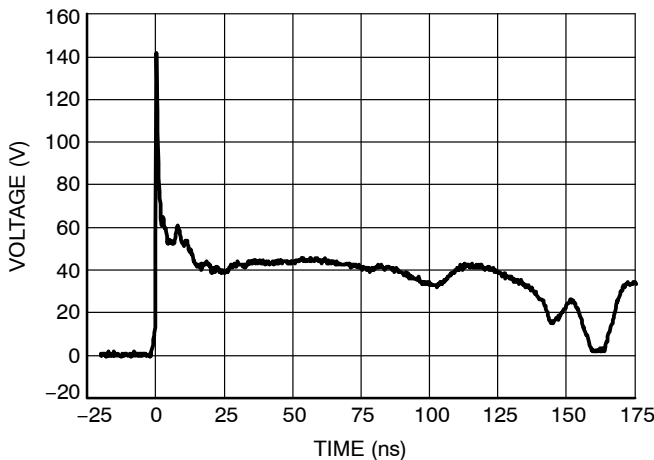


Figure 1. Typical IEC61000-4-2 + 8 kV Contact ESD Clamping Voltage

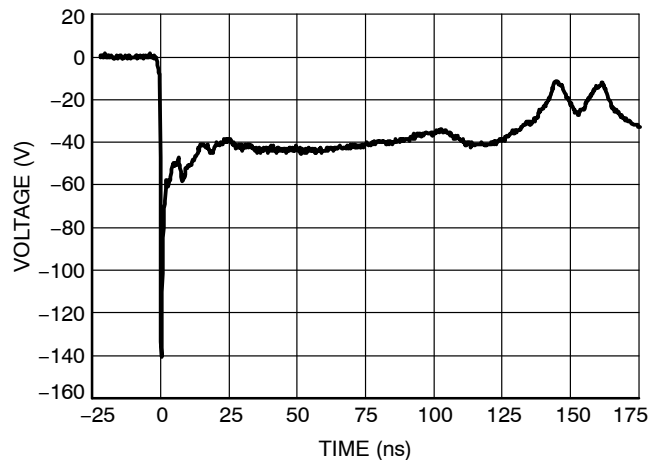


Figure 2. Typical IEC61000-4-2 - 8 kV Contact ESD Clamping Voltage

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IEC 61000-4-2 Spec.

Level	Test Voltage (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8



Figure 3. IEC61000-4-2 Spec

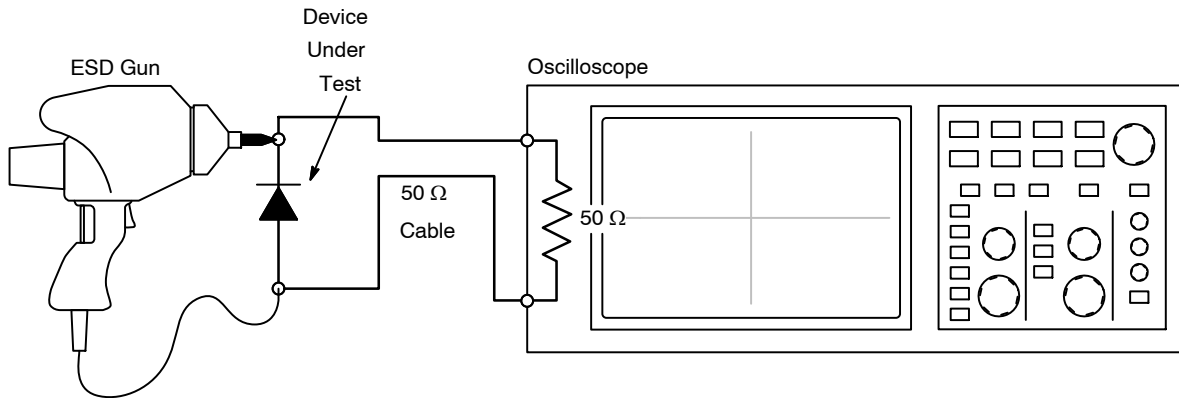


Figure 4. Diagram of ESD Clamping Voltage Test Setup

The following is taken from Application Note AND8308/D – Interpretation of Datasheet Parameters for ESD Devices.

ESD Voltage Clamping

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000-4-2 waveform. Since the IEC61000-4-2 was written as a pass/fail spec for larger

systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage at the device level. **onsemi** has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how **onsemi** creates these screenshots and how to interpret them please refer to AND8307/D.

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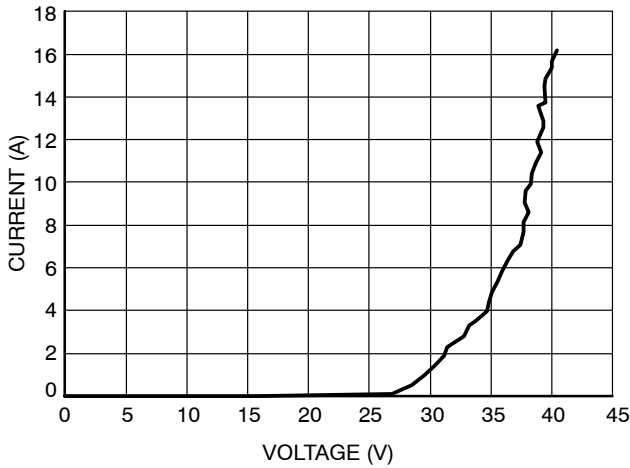


Figure 5. Typical Positive TLP IV Curve

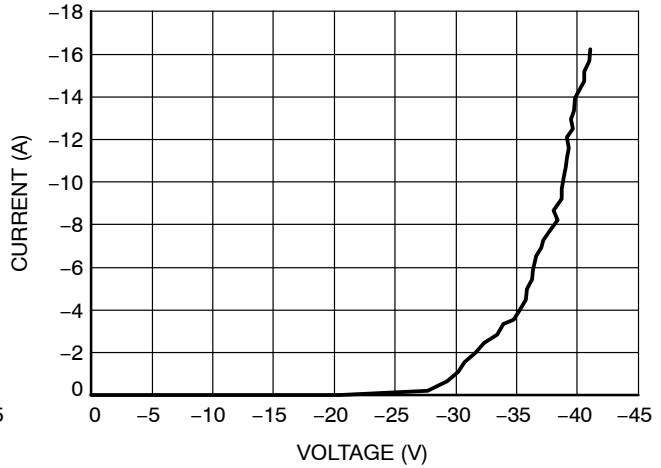


Figure 6. Typical Negative TLP IV Curve

NOTE: TLP parameter: $Z_0 = 50 \Omega$, $t_p = 100 \text{ ns}$, $t_r = 300 \text{ ps}$, averaging window: $t_1 = 30 \text{ ns}$ to $t_2 = 60 \text{ ns}$.

Transmission Line Pulse (TLP) Measurement

Transmission Line Pulse (TLP) provides current versus voltage (I-V) curves in which each data point is obtained from a 100 ns long rectangular pulse from a charged transmission line. A simplified schematic of a typical TLP system is shown in Figure 7. TLP I-V curves of ESD protection devices accurately demonstrate the product's ESD capability because the 10s of amps current levels and under 100 ns time scale match those of an ESD event. This is illustrated in Figure 8 where an 8 kV IEC 61000-4-2 current waveform is compared with TLP current pulses at 8 A and 16 A. A TLP I-V curve shows the voltage at which the device turns on as well as how well the device clamps voltage over a range of current levels.

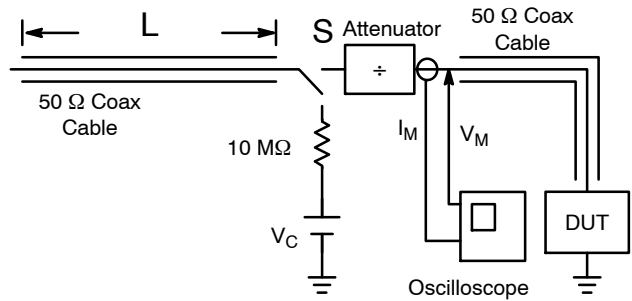


Figure 7. Simplified Schematic of a Typical TLP System

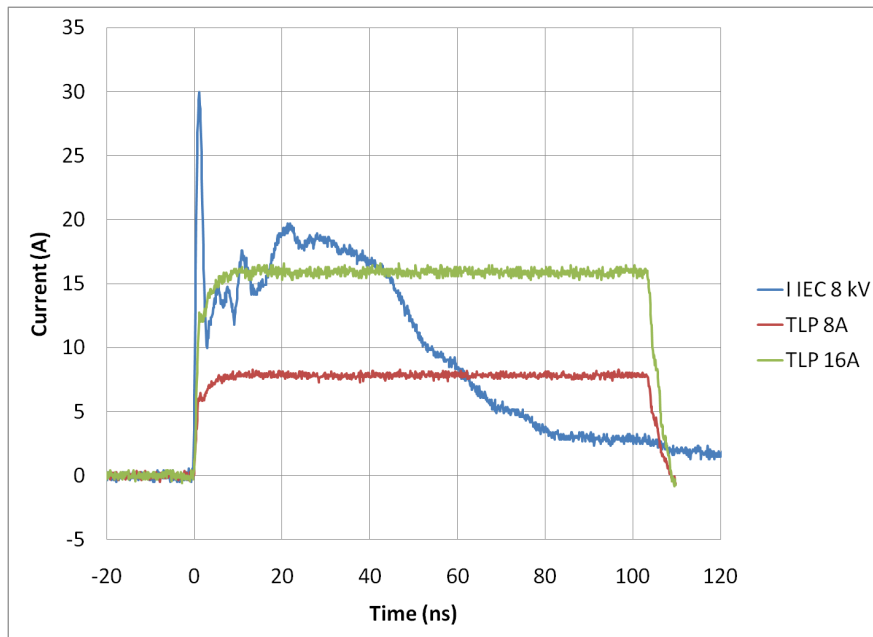


Figure 8. Comparison Between 8 kV IEC 61000-4-2 and 8 A and 16 A TLP Waveforms

TYPICAL CHARACTERISTICS

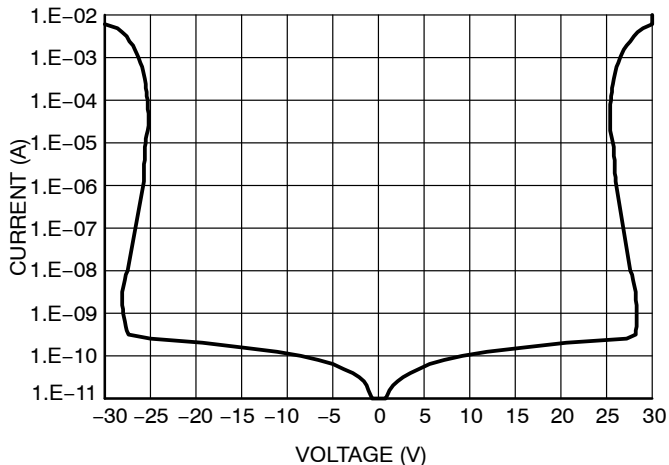


Figure 9. Typical IV Characteristics

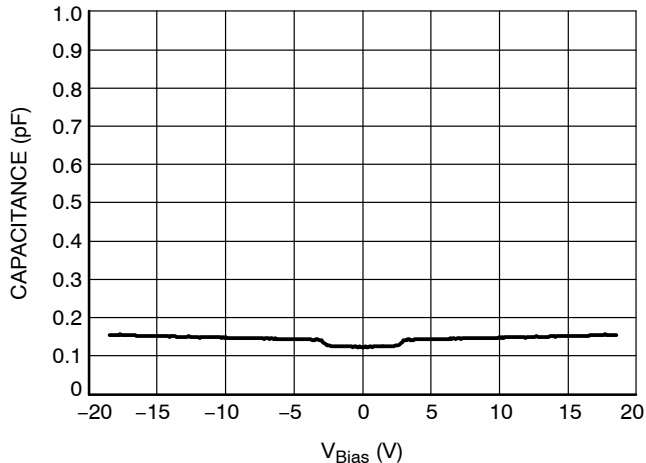


Figure 10. Typical CV Characteristics

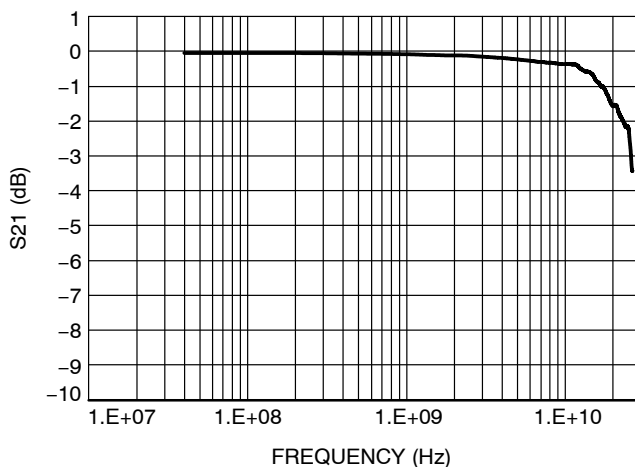


Figure 11. Typical Insertion Loss

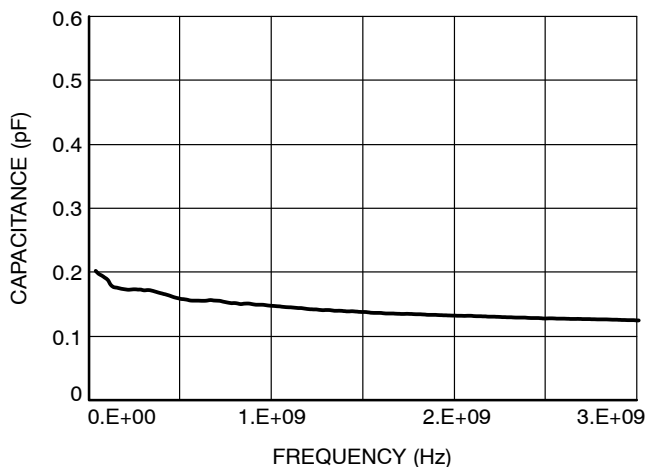
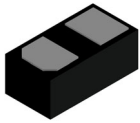


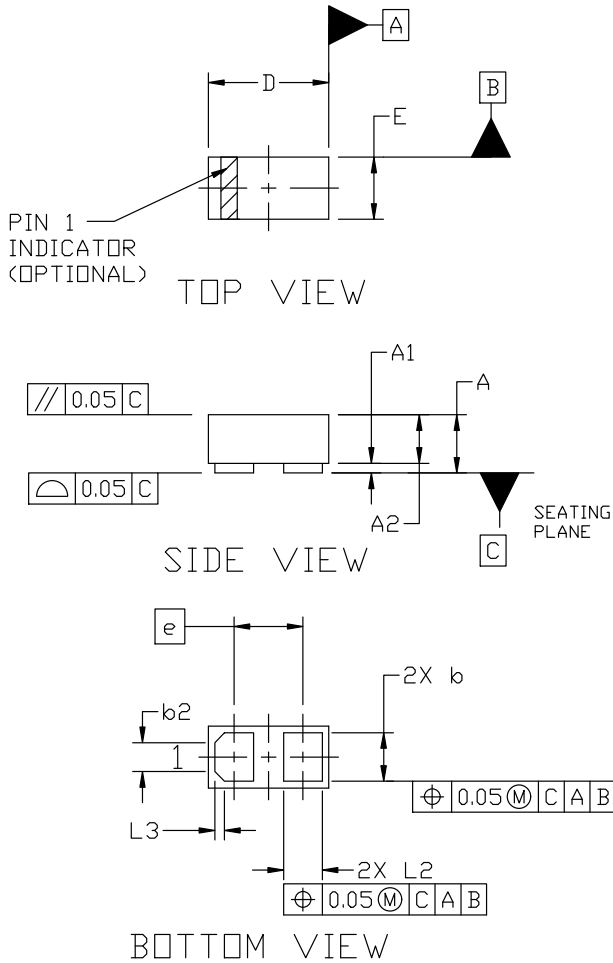
Figure 12. Typical Capacitance over Frequency

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



X3DFN2 0.62x0.32x0.24, 0.35P
CASE 152AF
ISSUE C

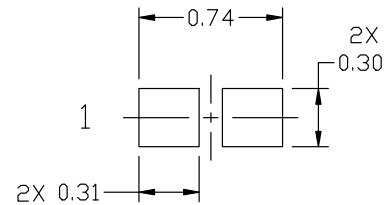
DATE 08 AUG 2023



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. 0201

MILLIMETERS			
DIM	MIN.	NOM.	MAX.
A	0.25	0.29	0.33
A1	0.00	---	0.05
A2	0.14	0.24	0.34
b	0.22	0.25	0.28
b2	0.150 REF		
D	0.58	0.62	0.66
E	0.28	0.32	0.36
e	0.355 BSC		
L2	0.17	0.20	0.23
L3	0.050 REF		



RECOMMENDED MOUNTING FOOTPRINT*

* For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



X = Specific Device Code
M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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